

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|---|---|------------------|---------|------------------|
| S1 | 2 | "20040155244" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:12 |
| S2 | 2 | ("6207586").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/05/17 15:16 |
| S3 | 11 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:14 |
| S4 | 9 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'gate insulating' with 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:37 |
| S5 | 198 | @ad<="20040114" and 'monocrystalline silicon' and 'thermal oxide' same 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:31 |
| S6 | 4 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'gate' with 'thermal oxide' with 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:38 |
| S7 | 22 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'gate insulating' and 'thermal oxide' and 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:52 |
| S10 | 116 | @ad<="20040114" and 'gate insulating' same 'thermal oxide' with 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:52 |
| S11 | 4 | @ad<="20040114" and 'tft;' and 'monocrystalline silicon' with 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:54 |
| S12 | 70 | @ad<="20040114" and 'monocrystalline silicon' with 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 15:54 |

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| S13 | 34 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/17 16:05 |
| S14 | 112 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'oxidized' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/03 07:58 |
| S15 | 1 | "20030116719".PN. | US-PGPUB | OR | ON | 2005/05/17 16:05 |
| S16 | 1 | "20030085397".PN. | US-PGPUB | OR | ON | 2005/05/17 16:05 |
| S17 | 138 | @ad<="20040114" and 'LCD' and 'monocrystalline silicon' and 'oxide' same 'nitride' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 08:40 |
| S18 | 15 | @ad<="20040114" and 'electro-optical' and 'monocrystalline silicon' and 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 08:40 |
| S19 | 9 | @ad<="20040114" and 'LCD' and 'monocrystalline silicon' and 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 08:40 |
| S20 | 131 | @ad<="20040114" and 'LCD' and 'monocrystalline silicon' and 'oxide' with 'nitride' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 08:40 |
| S22 | 1 | 'wo 200011709' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 09:05 |
| S23 | 1 | "5432625".PN. | USPAT; USOCR | OR | ON | 2005/05/18 10:28 |
| S24 | 3 | @ad<="20040114" and 'TFT' and 'monocrystal' with 'silicon' and 'insulating' with 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 14:25 |
| S25 | 102 | @ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 11:23 |
| S26 | 80 | @ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 15:58 |

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| S27 | 3 | ("6011275").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/05/18 11:52 |
| S28 | 9251 | @ad<="20040114" and (257/59). ccls. or (257/347).ccls. or (257/64). ccls. or (257/65).ccls. or (257/66). ccls. or (257/67).ccls. or (257/72). ccls. or (257/E21.413).ccls. or (257/E21.703).ccls. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 11:55 |
| S29 | 704 | @ad<="20040114" and (257/57). ccls. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 12:04 |
| S30 | 1155 | @ad<="20040114" and (257/79). ccls. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/18 12:04 |
| S31 | 81 | @ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 14:26 |
| S32 | 3 | @ad<="20040114" and 'TFT' and 'monocrystal' with 'silicon' and 'insulating' with 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 16:02 |
| S33 | 36 | @ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd' and 'LDD' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:20 |
| S34 | 9 | ("6077731").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/08/02 14:58 |
| S45 | 110 | @ad<="20040114" and 'single crystal' with 'silicon' same 'mono' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 15:55 |
| S46 | 81 | @ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 15:58 |

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| S47 | 855 | @ad<="20040114" and 'TFT' and 'monocrystalline' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 16:02 |
| S48 | 61 | @ad<="20040114" and 'TFT' and 'monocrystalline' and 'gate' with 'thermal' with 'cvd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 16:05 |
| S49 | 7 | @ad<="20040114" and 'TFT' and 'monocrystalline' and 'gate' with 'thermal' with 'cvd' and 'idd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 16:05 |
| S50 | 38 | @ad<="20040114" and 'TFT' and 'monocrystalline' and 'thermal' with 'cvd' and 'idd' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/02 16:05 |
| S51 | 0 | @ad<="20040114" and 'TFT' and 'insulating gate' with 'capacitor line' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/03 07:59 |
| S52 | 183 | @ad<="20040114" and 'TFT' and 'gate insulating' same 'capacitor line' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/03 08:00 |
| S53 | 136 | @ad<="20040114" and 'TFT' and 'gate insulating' with 'capacitor line' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/03 08:00 |
| S54 | 31 | @ad<="20040114" and 'TFT' with 'gate insulating' with 'capacitor line' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/08/03 08:00 |
| S55 | 183 | @ad<="20040114" and 'TFT' and ('monocrystalline' or 'monocrystal' or 'crystallinity') with 'silicon' and 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 15:57 |
| S56 | 71 | @ad<="20040114" and 'TFT' and ('monocrystalline' or 'monocrystal' or 'crystallinity') with 'silicon' and 'thermal oxide' same 'cvd' same 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 15:59 |
| S57 | 1 | @ad<="20040114" and 'TFT' same 'monocrystalline' with 'silicon' and 'thermal oxide' same 'cvd' same 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 16:00 |

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| S58 | 8 | @ad<="20040114" and 'TFT' same 'monocrystalline' with 'silicon' and 'thermal oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 16:02 |
| S59 | 200 | @ad<="20040114" and 'TFT' same 'monocrystalline' with 'silicon' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 16:02 |
| S60 | 128 | @ad<="20040114" and 'TFT' with 'monocrystalline' with 'silicon' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 16:02 |
| S61 | 111 | @ad<="20040114" and 'TFT' with 'monocrystalline silicon' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 16:07 |
| S62 | 37 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' same 'channel' and 'LDD' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/05 16:22 |
| S63 | 8 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' same 'active layer' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:13 |
| S64 | 0 | @ad<="20040114" and 'TFT' same 'monocrystalline semiconductor' with 'active layer' same 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:13 |
| S65 | 0 | @ad<="20040114" and 'TFT' same 'monocrystalline' with 'active layer' same 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:14 |
| S66 | 0 | @ad<="20040114" and 'TFT' same 'monocrystalline' with 'active' same 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:14 |
| S67 | 0 | @ad<="20040114" and 'TFT' and 'monocrystalline' with 'active' same 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:14 |
| S68 | 11 | @ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:14 |

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| S69 | 0 | @ad<="20040114" and 'TFT' and 'monocrystalline' with 'active' and 'thermal oxide' same 'cvd' with 'oxide' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:14 |
| S70 | 8 | @ad<="20040114" and 'TFT' and 'mono' with 'crystal' with 'silicon' and ('insulating' or 'dielectric') with 'thermal oxide' and ('oxide' or 'nitride') with 'cvd' and 'LDD' | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/12/06 08:21 |